

4V Drive Pch MOSFET

RP1E050RP

Structure

Silicon P-channel MOSFET

● Features

- 1) Low On-resistance.
- 2) High power package.
- 3) 4V drive.

Application

Switching

Packaging specifications

	Package	Taping	
Type	Code	TR	
	Basic ordering unit (pieces)	1000	
RP1E050R	0		

● Absolute maximum ratings (Ta = 25°C)

Paran	Symbol	Limits	Unit	
Drain-source voltage		V_{DSS}	-30	V
Gate-source voltage		V_{GSS}	±20	V
Drain current	Continuous	I_D	±5	Α
	Pulsed	I _{DP} *1	±20	Α
Source current (Body Diode)	Continuous	I _S	-1.6	Α
	Pulsed	I _{SP} *1	-20	Α
Power dissipation		P _D *2	2.0	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

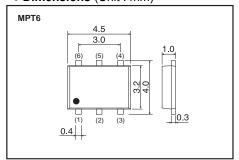
^{*1} Pw≤10µs, Duty cycle≤1%

• Thermal resistance

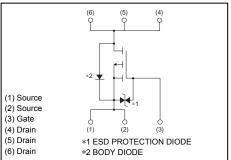
Parameter	Symbol	Limits	Unit
Channel to Ambient	Rth (ch-a)*	62.5	°C/W

^{*}Mounted on a ceramic board.

Dimensions (Unit : mm)



• Inner circuit



^{*2} Mounted on a ceramic board.

● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	±10	μA	$V_{GS}=\pm20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-30	1	-	٧	I _D =-1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	1	1	-1	μA	V _{DS} =-30V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	-1.0	1	-2.5	>	V _{DS} =-10V, I _D =-1mA
Static ducin accuracy on state		ı	36	50	mΩ	I _D =-5A, V _{GS} =-10V
Static drain-source on-state resistance	R _{DS (on)}	-	52	72		$I_D = -2.5A$, $V_{GS} = -4.5V$
resistance		1	58	80		I _D =-2.5A, V _{GS} =-4.0V
Forward transistor admittance	I Y _{fs} ľ	4	1	-	S	I _D =-5A, V _{DS} =-10V
Input capacitance	C _{iss}	-	850	-	pF	V _{DS} =-10V
Output capacitance	C _{oss}	1	120	-	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	1	120	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	1	9	ı	ns	I _D =-2.5A, V _D ; −15V
Rise time	t _r *	-	25	-	ns	V _{GS} =-10V
Turn-off delay time	t _{d(off)} *	1	55	-	ns	R_L =6.0 Ω
Fall time	t _f *	1	30	ı	ns	$R_G=10\Omega$
Total gate charge	Q _g *	1	9.2	-	nC	I _D =–5A, V _{DD} ≒–15V
Gate-source charge	Q _{gs} *	-	2.4	-	nC	V_{GS} =-5V R _L =3.0 Ω
Gate-drain charge	Q _{gd} *	-	3.6	-	nC	R_G =10 Ω

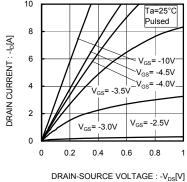
^{*}Pulsed

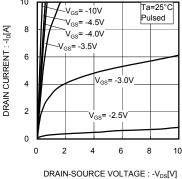
●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward Voltage	V _{SD} *	-	-	-1.2	V	I _s =-5A, V _{GS} =0V

^{*}Pulsed

Electrical characteristics curves





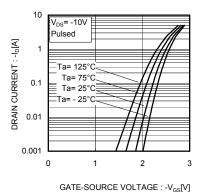
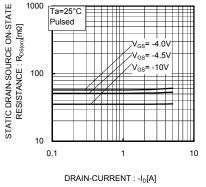
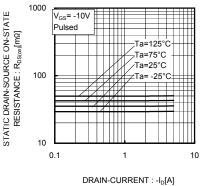


Fig.1 Typical Output Characteristics(I)

Fig.2 Typical Output Characteristics(${\rm I\hspace{-.1em}I}$)

Fig.3 Typical Transfer Characteristics





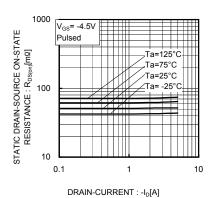
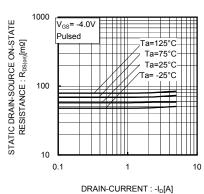
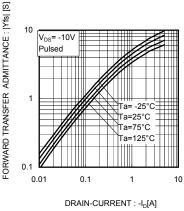


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)





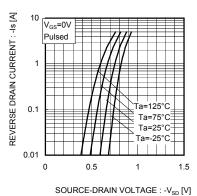


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

Fig.8 Forward Transfer Admittance vs. Drain Current

Fig.9 Reverse Drain Current vs. Sourse-Drain Voltage

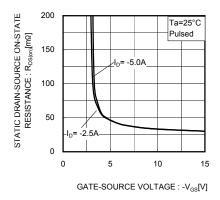


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

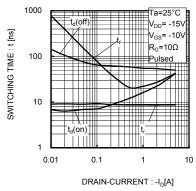
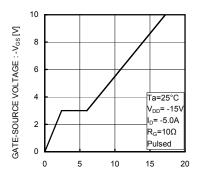
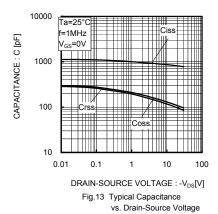


Fig.11 Switching Characteristics



TOTAL GATE CHARGE : Qg [nC]
Fig.12 Dynamic Input Characteristics



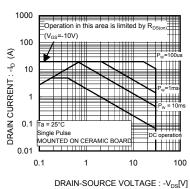


Fig.14 Maximum Safe Operating Area

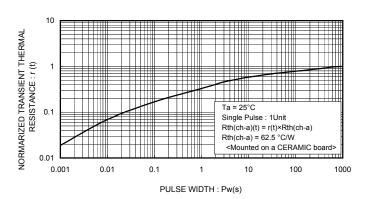


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

Data Sheet

Measurement circuits

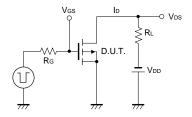


Fig.1-1 Switching Time Measurement Circuit

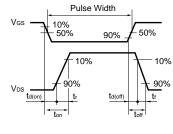


Fig.1-2 Switching Waveforms

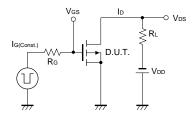


Fig.2-1 Gate Charge Measurement Circuit

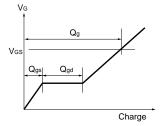


Fig.2-2 Gate Charge Waveform

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